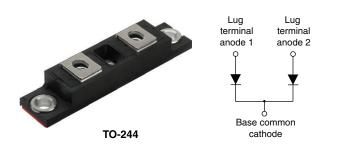
Vishay Semiconductors

High Performance Schottky Rectifier, 200 A



www.vishay.com

PRIMARY CHARACTERISTICS				
I _{F(AV)}	200 A			
V _R	45 V			
Package	TO-244			
Circuit configuration	Two diodes common cathode			

FEATURES

- 150 °C T_J operation
- · Center tap module
- · Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- UL approved file E222165
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

The VS-200CNQ... center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES U				
I _{F(AV)}	Rectangular waveform	200	А			
V _{RRM}		45	V			
I _{FSM}	t _p = 5 μs sine	26 000	А			
V _F	100 A _{pk} , T _J = 125 °C (per leg)	0.52	V			
TJ	Range	-55 to +150	°C			

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-200CNQ045PbF	UNITS	
Maximum DC reverse voltage	V _R	45	N/	
Maximum working peak reverse voltage	V _{RWM}	45	v	

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average	per leg		50 % duty cycle at T_{C} = 116 °C, rectangular waveform			100	
forward current See fig. 5	per device	IF(AV)			200	A	
Maximum peak one cyc	mum peak one cycle repetitive surge current per leg		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	26 000	- A	
See fig. 7	rent per leg	IFSM	10 ms sine or 6 ms rect. pulse rated V_{RRM} applied		1550		
Non-repetitive avalanche	e energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 17 A, L = 1 mH		135	mJ	
Repetitive avalanche cu	rrent per leg	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		20	А	

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Threshold voltage

Forward slope resistance

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0.27

2.0

5200

7.0

10 000

UNITS

٧

mΑ

٧

mΩ

pF

nΗ

V/µs

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS V			
Maximum forward voltage drop per leg See fig. 1	V _{FM} ⁽¹⁾	100 A	T,I = 25 °C	0.55	
		200 A	1j=25 0	0.73	
		100 A	T,I = 125 °C	0.52	
		200 A	$1_{\rm J} = 125$ C	0.69	
Maximum reverse leakage current per leg See fig. 2	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	10	
		T _J = 125 °C	VR - naieu VR	800	

 $T_J = T_J$ maximum

Rated V_R

V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C

From top of terminal hole to mounting plane

V_{F(TO)}

r_t CT

 L_S

dV/dt

Maximum voltage rate of change Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

Maximum junction capacitance per leg

Typical series inductance per leg

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temper	ature range	T _J , T _{Stg}	- 55	-	150	°C
Thermal resistance, junction to case	per leg		-	-	0.38	°C/W
	per module	R _{thJC}	-	-	0.19	
Thermal resistance, case to heatsink		R _{thCS}	-	0.10	-	
Weight			-	68	_	g
				2.4		oz.
Mounting torque			35.4 (4)	-	53.1 (6)	
Mounting torque center hole			30 (3.4)	-	40 (4.6)	lbf ⋅ in (N ⋅ m)
Terminal torque			30 (3.4)	-	44.2 (5)	()
Vertical pull			-	-	80	- lbf ⋅ in
2" lever pull			-	-	35	חו י ועו

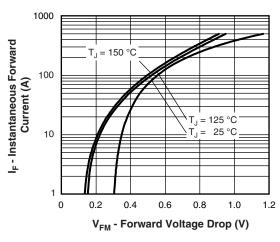


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

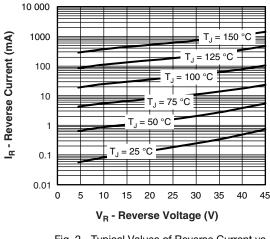


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

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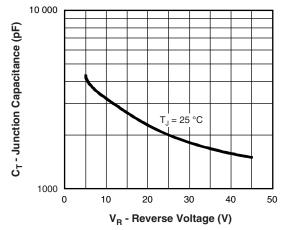


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

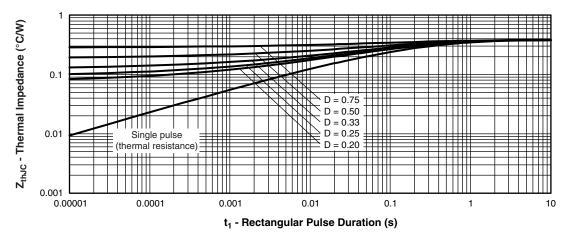
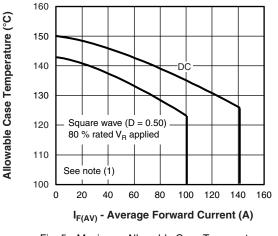
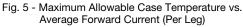


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)





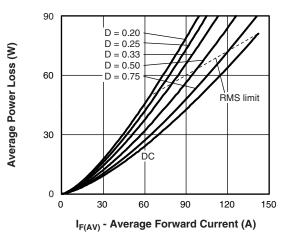


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

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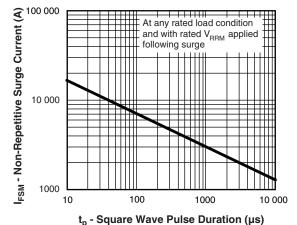


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

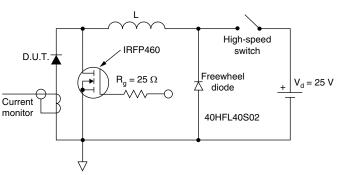
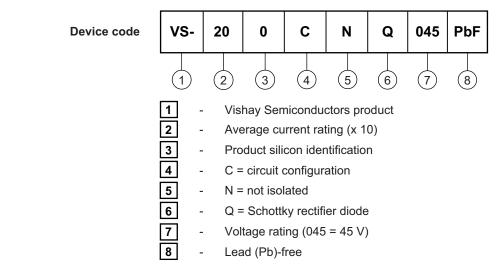


Fig. 8 - Unclamped Inductive Test Circuit

Note

 $\begin{array}{l} \mbox{Pd} = \mbox{forward power loss} = \mbox{I}_{F(AV)} \times \mbox{V}_{FM} \mbox{ at } (\mbox{I}_{F(AV)}/\mbox{D}) \mbox{ (see fig. 6);} \\ \mbox{Pd}_{REV} = \mbox{inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{ (1 - D); } \mbox{I}_{R} \mbox{ at } \mbox{V}_{R1} = 80 \ \% \mbox{ rated } \mbox{V}_{R} \end{array}$

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⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

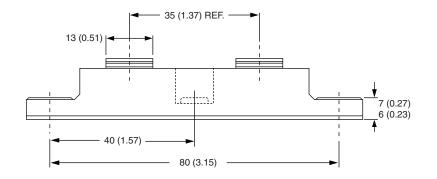


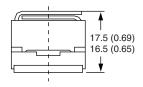


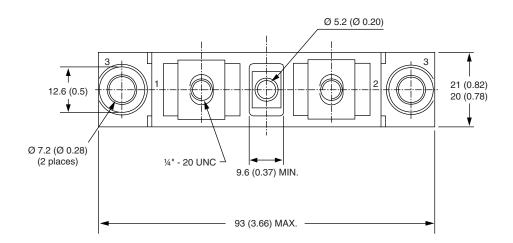
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TO-244

DIMENSIONS in millimeters (inches)









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